Silicon N-Channel MOS FET

HITACHI

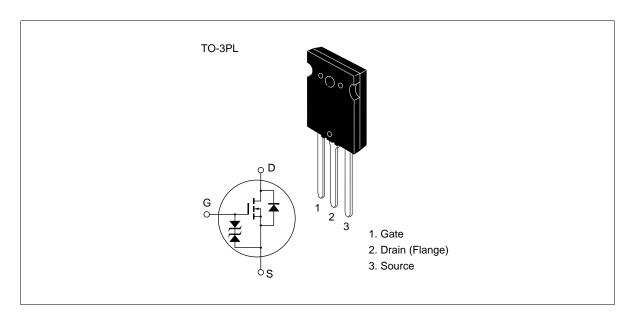
Application

High speed power switching

Features

- Low on-resistance
- High speed switching
- Low drive current
- No secondary breakdown
- Suitable for switchingregulator, DC-DC converter

Outline





Absolute Maximum Ratings ($Ta = 25^{\circ}C$)

Item		Symbol	Ratings	Unit
Drain to source voltage	K1836	$V_{\scriptscriptstyle DSS}$	450	V
	K1837		500	
Gate to source voltage		V _{GSS}	±30	V
Drain current		I _D	50	Α
Drain peak current		I _{D(pulse)} *1	200	Α
Body to drain diode reverse drain current		I _{DR}	50	Α
Channel dissipation		Pch*2	250	W
Channel temperature		Tch	150	°C
Storage temperature		Tstg	-55 to +150	°C

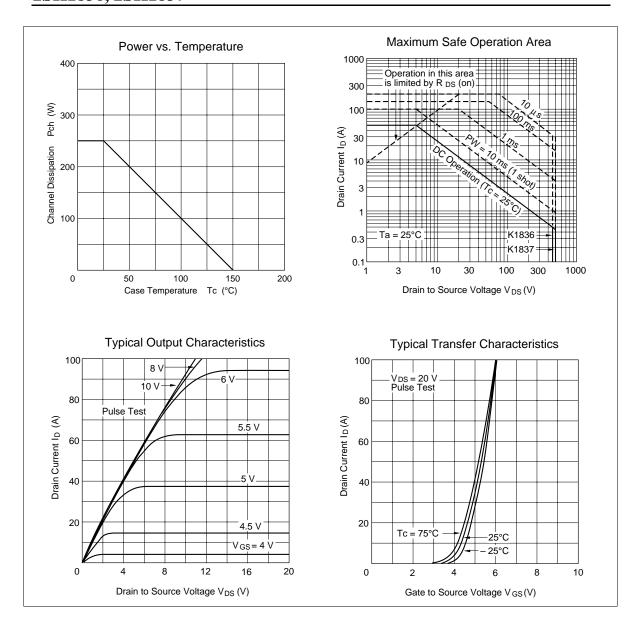
Notes 1. PW \leq 10 μ s, duty cycle \leq 1 %

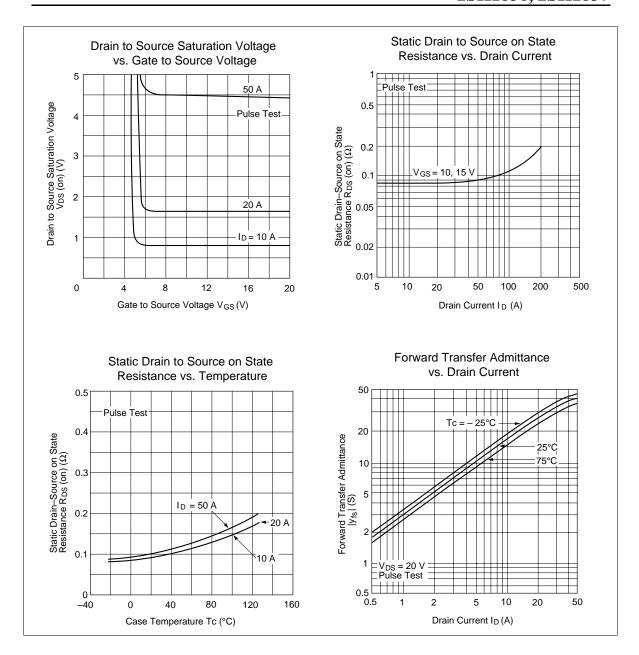
2. Value at Tc = 25 $^{\circ}$ C

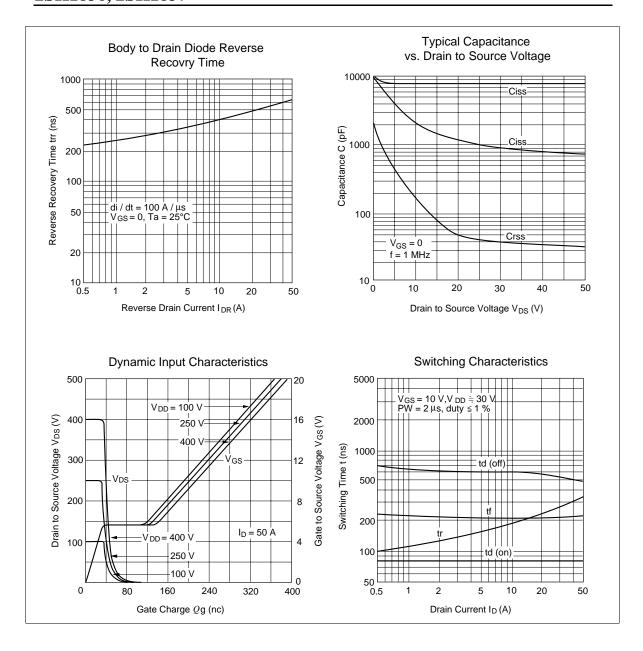
Electrical Characteristics (Ta = 25°C)

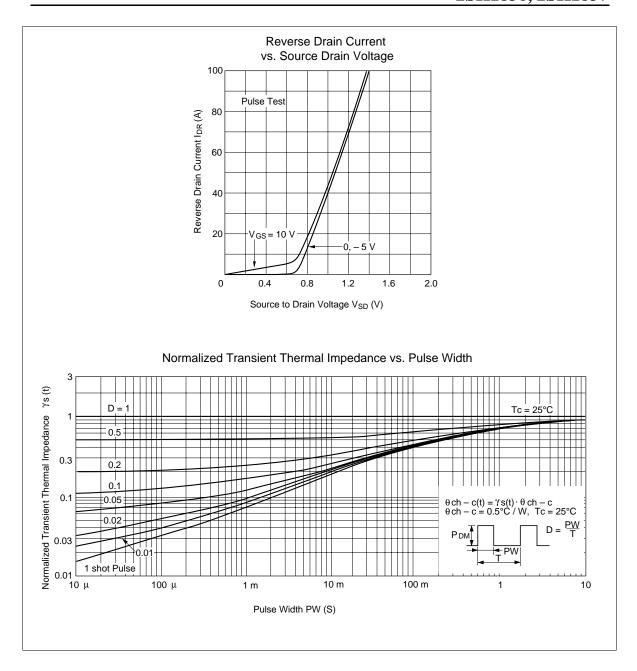
Item		Symbol	Min	Тур	Max	Unit	Test conditions
Drain to source	K1836	$V_{(BR)DSS}$	450	_	_	V	$I_D = 10 \text{ mA}, V_{GS} = 0$
breakdown voltage	K1837	_	500	_	_	_	
Gate to source b	reakdown	$V_{(BR)GSS}$	±30	_	_	V	$I_{G} = \pm 100 \ \mu A, \ V_{DS} = 0$
Gate to source leak current		I _{GSS}	_	_	±10	μΑ	$V_{GS} = \pm 25 \text{ V}, V_{DS} = 0$
Zero gate	K1836	I _{DSS}	_	_	250	μΑ	$V_{DS} = 360 \text{ V}, V_{GS} = 0$
voltage drain current	K1837						$V_{DS} = 400 \text{ V}, V_{GS} = 0$
Gate to source c	utoff voltage	$V_{GS(off)}$	2.0	_	3.0	V	$I_{D} = 1 \text{ mA}, V_{DS} = 10 \text{ V}$
Static drain to	K1836	R _{DS(on)}	_	0.08	0.10	Ω	I _D = 25 A
source on state resistance	K1837		_	0.085	0.11		V _{GS} = 10 V* ¹
Forward transfer	admittance	y _{fs}	22	35	_	S	$I_D = 25 \text{ A}$ $V_{DS} = 10 \text{ V}^{*1}$
Input capacitanc	е	Ciss	_	8150	_	pF	V _{DS} = 10 V
Output capacitar	nce	Coss	_	2100	_	pF	$V_{GS} = 0$
Reverse transfer	capacitance	Crss	_	180	_	pF	f = 1 MHz
Turn-on delay tin	ne	t _{d(on)}	_	80	_	ns	I _D = 25 A
Rise time		t _r	_	250	_	ns	V _{GS} = 10 V
Turn-off delay tin	ne	t _{d(off)}	_	550	_	ns	$R_L = 1.2 \Omega$
Fall time		t _f	_	220	_	ns	<u> </u>
Body to drain did voltage	ode forward	V _{DF}	_	1.1	_	V	I _F = 50 A, V _{GS} = 0
Body to drain did recovery time	ode reverse	t _{rr}	_	620	_	ns	$I_F = 50 \text{ A}, V_{GS} = 0,$ $di_F / dt = 100 \text{ A} / \mu \text{s}$

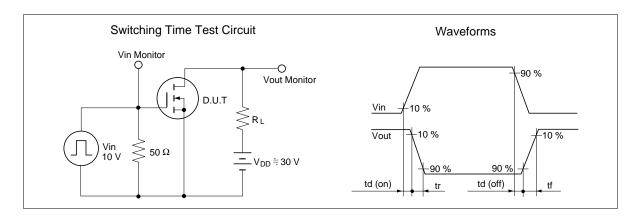
Note 1. Pulse Test



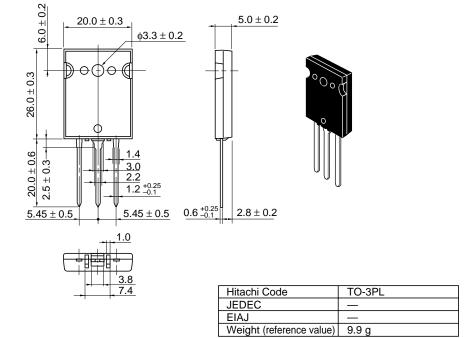












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